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PATENT NUMBER and
ISSUE DATE

U.S. UTILITY Patent Application

APPL NUM 10046741	FILING DATE 01/17/2002	CLASS 438	SUBCLASS 479	GAU 2812	EXAMINER Mulpuri
**APPLICANTS: Ono Yoshinobu; Hata Masahiko;					
**CONTINUING DATA VERIFIED: <i>none</i> <i>SM</i>					
** FOREIGN APPLICATIONS VERIFIED: JAPAN 2001-009144 01/17/2001 <i>SM</i>					
PG-PUB <input type="checkbox"/> DO NOT PUBLISH <input type="checkbox"/>		RESCIND <input type="checkbox"/>			
Foreign priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no		35 USC 119 conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no		ATTORNEY DOCKET NO 3885-0103P	
Verified and Acknowledged Examiners's initials <i>SM</i>					
TITLE : Method for fabricating III-V compound semiconductor					

U.S. DEPT. OF COMM./PAT. & TM.-PTO-436L (Rev. 12-94)

NOTICE OF ALLOWANCE MAILED		Assistant Examiner		CLAIMS ALLOWED	
				Total Claims	Print Claim for O.G.
ISSUE FEE		Primary Examiner		DRAWING	
Amount Due	Date Paid			Sheets Drwg.	Figs. Drwg.
<input type="checkbox"/> TERMINAL DISCLAIMER		PREPARED FOR ISSUE		Application Examiner	
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